Electronic property of Na-doped epitaxial graphenes on SiC

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The electronic property of epitaxial graphenes with Na adsorption or intercalation is studied with the use of pseudopotential density functional method. It is found that the charge transfer and the Na binding energy show strong coverage dependence. Calculated energetics shows that Na prefers the intercalation between the buffer and top graphene layers to the adsorption on top graphene layer. The buffer layer is inert to Na adsorption on top graphene layer but it is charged when Na atoms are intercalated. This indicates that the conduction of epitaxial graphenes can be affected significantly by Na intercalation. © 2009 American Institute of Physics. [DOI: 10.1063/1.3120274]

Many interesting physics of graphene have been reported and attracted great attention of scientists and engineers in various fields. Graphene is truly a two-dimensional (2D) structural material with linear electronic bands near the Fermi level. The charge carriers thus behave like massless Dirac fermions with definite chirality in 2D. This unique structural and electronic property has stimulated many interesting experiments such as quantum Hall effect. Constrict nanostructures of graphene known as graphene nanoribbons also exhibit very rich and interesting physics such as size- and orientation-dependent electronic structures. In parallel, there have been great efforts to develop electronic devices that utilize the large carrier mobility and inertness to impurity scattering. For practical application of graphenes to electronic devices, it is necessary to resolve several key issues such as reproducible growth of single graphene layers, gap opening, and doping of the graphenes. Single layer graphenes are now obtained by mechanical peeling of graphite or by epitaxial growth on 6H–SiC surfaces. Atomic adsorption is a straightforward way to change the carrier density or modify the electronic structure of graphene. Alkaline metals are well-known elements that absorb on or intercalate into graphite to donate electrons. In this paper we studied the electronic property of epitaxial graphene with Na adsorption or intercalation using pseudopotential density functional method.

Computation was carried out using the pseudopotential density functional method with plane-wave basis set. The exchange-correlation of electrons was treated within the generalized gradient approximation as implemented by Perdew–Burke–Enzelhof. The cutoff energy for the expansion of wave functions and potentials in the plane-wave basis was chosen to be 400 eV, and the Brillouin zone sampling was done with the Monkhorst–Pack special k-point method with a grid of 5 × 5 × 1 for the \( \sqrt{3} \times \sqrt{3} \times 30^\circ \) phase. We used the projector augmented wave pseudopotentials as provided by the Vienna Ab-initio Simulation Package. The atomic relaxation was carried out until the Helmann–Feynman forces were less than 0.02 eV/A. The vacuum layer in the supercell used in our calculations is set to be 8 Å, which is enough to minimize the artificial interlayer interaction.

First, we studied the sodium atom adsorption on freestanding single layer graphenes. Figures 1(a) and 1(b) summarize our calculations of charge transfer from sodium to graphene and the Na adsorption energy at varying Na coverage. Among the top of carbon, the bridge site, and the hexagon center, sodium atoms bind to the hexagon center most strongly (calculated adsorption energies are 0.52, 0.43, and 0.67 eV, respectively). The 1 ML of Na on graphene is defined as one Na atom per five C atoms. Our calculations [Fig. 1(a)] show that the amount of charge transfer per Na atom is almost one electron until 0.1 ML and then decreases as an inverse of \( \rho_{Na} \) (Na density or coverage) at higher coverages. The charge transfer and Na adsorption energy at varying Na coverage.

FIG. 1. (Color online) (a) Calculated charge transfer from Na to graphene per sodium atom (green triangles) or per carbon atom (orange squares) with analytic fitting curves (see the text) and (b) the adsorption energy of Na at varying sodium coverage on graphene. (c) Atomic structure of sodium (denoted by large red balls) on graphene (small gray balls) at 1.04 ML coverage. Calculated Na interatomic distance is also shown. (d) Corresponding density of states (DOS) for the structure shown in (c). Partial DOS obtained by projecting onto graphene (blue) and Na (red) are also shown for comparison.
verage. This $1/\rho_{Na}$ behavior is obtained by maximizing the energy gain from the transfer, $E_{ad} = (E_r - \bar{E})n + cn^2\rho_{Na}$, where $E_r$, $n$, and $\bar{E}$ are the energy level of Na 3s state [or $-(\text{Na ionization energy})$], the electron transfer per Na, and the average electronic energy of transferred electrons in graphene (this depends on $n$ and $\rho_{Na}$), respectively. The last term in $E_{ad}$ is the Coulomb energy with $c$ being a constant. Assuming a linear density of states (DOS) of graphene $\sim D(E - E_0)$ with $D$ and $E_0$ being constants, to express $\bar{E}$ as a function of $n$ and $\rho_{Na}$, the energy gain can be written as

$$E_{ad} = (E_r - E_0)n - \frac{2}{3} \sqrt{\frac{2\rho_{Na}}{D}} n^{3/2} + cn^2\rho_{Na}.$$ 

The maximum condition of $E_{ad}$ with respect to $n$ gives the $1/\rho_{Na}$ behavior (or the constant charge transfer per carbon). As the coverage increases further, the inter-Na interaction first lowers Na 3s level by the effect of ionic Na potential and next broadens the level to form a metallic band by wave-function overlap. This lowering and then rising of the energy level of Na 3s state drives the charge transfer per Na from $1/\rho_{Na}$, making a dip at around 0.6 ML in the charge transfer per carbon. The dependency of calculated adsorption energies of Na on coverage also fits into the above equations at low coverage (<0.28 ML) as it decreases almost as $1/\rho_{Na}$. At higher coverage, Na atoms start to form metallic bonding with each other and the overall (adsorption) energy appears to increase resultantly. Figure 1(c) is the atomic arrangement for the 1.04 ML sodium on top of graphene and Fig. 1(d) shows the partial and total DOS for this configuration. From calculated DOS, we observe that the free electron states (flat Na partial DOS) are not empty, which indicates that Na metallic bonds are formed at large sodium coverage.

Next, we studied Na adsorption on graphenes epitaxially grown on SiC (0001) surface. It is well-known that SiC (0001) surface upon heating turns into carbon-rich surface, namely, $6\times3\times6\sqrt{3}$R30° buffer layer (or reconstructed substrate) and then single layer graphenes at further heating. Instead of using the large size $6\times3\times6\sqrt{3}$R30° structure, here we carried out calculations of Na adsorption on a smaller-sized structure of $\sqrt{3} \times \sqrt{3}$R30° shown in Fig. 2 for computational convenience (we expect that the adsorption properties of Na is not sensitive to the size of the structure because of free electronlike nature of Na atom). As not only single graphene layers but also buffer layers are exposed to Na deposition in experiment, we studied Na adsorption for all available configurations: on the buffer layer (without upper graphene layer), on top-most graphene layer and the intercalation between graphene and buffer layers.

As Na coverage of 1 ML is not commensurate with underlying SiC, we chose 0.63 ML coverage with Na atoms adsorbing on the hexagon centers. Figure 2 shows the atomic arrangement of the clean or Na-adsorbed (0.63 ML) buffer layer (without upper graphene layer) together with calculated band structures for corresponding configurations. The buffer-layer $\pi$ bands are completely empty without Na adatoms [Fig. 2(b)] in agreement with previous calculations. We also observe a flat band near the Fermi level that comes from the top Si dangling bonds. For Na adsorption, two inequivalent hexagon centers are available due to underlying SiC substrates. Calculated adsorption energies on the two hexagon centers [Figs. 2(c) and 2(d)] are 0.84 and 0.78 eV, respectively. Two parabolic $\pi$ bands from the buffer layer near the $\Gamma$-point are now partially occupied by the electrons transferred from sodium atoms. The underlying SiC substrates also affect the degeneracy of the buffer layer $\pi$ bands. Figure 2(c) shows that the degeneracy at $\Gamma$-point is preserved because the original atomic symmetry is still preserved even upon Na adsorption. Whereas, the bands are split for the Na adsorption shown in Fig. 2(d). While the Na adsorption shown in Fig. 2(c) is energetically more favorable than in Fig. 2(d), the energy difference is so small that we expect a broadening in the $\pi$ band from the buffer layer.

Next, we studied the adsorption and the intercalation of Na in graphene-buffer layer structure on SiC substrate. Figure 3 shows the graphene-$\sqrt{3} \times \sqrt{3}$R30° buffer layer with or without Na adsorption or intercalation between buffer and top graphene layers. Without Na [Fig. 3(a)], the graphene $\pi$ band shifts down due to charge transfer from buffer to top graphene layer, which is consistent with previous reports. When Na adsors on top graphene layer [Fig. 3(b)], the graphene $\pi$ band shifts down further due to additional charge transfer from Na atoms. We also observe a parabolic band near $\Gamma$-point that originates from Na 3s states. This behavior is very similar to that for the Na adsorption on isolated graphene. However, the adsorption energy in Fig. 3(b) case is calculated to be about 0.73 eV, which is larger than that in isolated graphene of about 0.61 eV, for 0.63 ML Na cover-
In summary, we studied the electronic property of epitaxial graphene with Na intercalation or adsorption. A strong coverage dependence is found both in Na adsorption energy and the charge transfer from Na to graphene that decrease as an inverse of Na coverage at low coverage. The buffer layer is found to be inert to Na adsorption on top layer graphene but become conducting upon Na intercalation. Our calculations indicate that the conduction of epitaxial graphene with Na doping can exhibit a contrasting behavior depending on whether Na adsorbs on top layer graphene or intercalates into buffer and graphene layers.

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